

Midium Power Transistors (30V / 5A)

2SCR542P

Structure

NPN Silicon epitaxial planar transistor

Features

- 1) Low saturation voltage, typically $V_{CE (sat)} = 0.4V (Max.) (I_C / I_B = 2A / 100mA)$
- 2) High speed switching

Applications

Driver

Packaging specifications

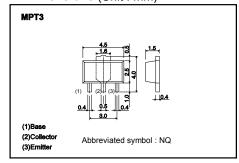
	Package	Taping
71	Code	T100
	Basic ordering unit (pieces)	1000
2SCR542P		0

● Absolute maximum ratings (Ta = 25°C)

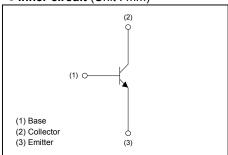
Para	Symbol	Limits	Unit	
Collector-base voltage		V_{CBO}	30	V
Collector-emitter voltage		V_{CEO}	30	V
Emitter-base voltage		V_{EBO}	6	V
Collector current	DC	Ic	5	Α
	Pulsed	I _{CP} *1	10	Α
Power dissipation		P _D *2	0.5	W
		P _D *3	2	W
Junction temperature		T_j	150	°C
Range of storage temperature		T_{stg}	-55 to 150	°C

^{*1} Pw=10ms, Single Pulse

• Dimensions (Unit : mm)



• Inner circuit (Unit : mm)



^{*2} Each terminal mounted on a recommended land.

^{*3} Mounted on a ceramic board. (40x40x0.7mm³)

2SCR542P Data Sheet

●Electrical characteristic (Ta = 25°C)

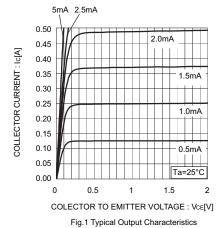
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-emitter breakdown voltage	BV _{CEO}	30	-	-	V	I _C = 1mA	
Collector-base breakdown voltage	BV _{CBO}	30	-	-	V	I _C = 100μA	
Emitter-base breakdown voltage	BV_{EBO}	6	-	-	٧	I _E = 100μA	
Collector cut-off current	I _{CBO}	-	-	1	μA	V _{CB} = 30V	
Emitter cut-off current	I _{EBO}	-	-	1	μA	V _{EB} = 4V	
Collector-emitter staturation voltage	V _{CE(sat)} *1	-	200	400	mV	I _C = 2A, I _B = 100mA	
DC current gain	h _{FE}	200	-	500	-	V_{CE} = 2V, I_{C} = 500mA	
Transition frequency	f _T *1	ı	250	ı	MHz	V _{CE} = 10V I _E =-100mA, f=100MHz	
Collector output capacitance	C _{ob}	ı	25	ı	pF	V _{CB} = 10V, I _E =0A f=1MH z	
Turn-on time	t _{on} *2	1	40	-	ns	I _C = 2.5A,I _{B1} = 250mA, I _{B2} =-250mA,V _{CC} ~ 10V	
Storage time	t _{stg} * ₂	-	320	-	ns		
Fall time	t _f *2	-	25	-	ns		

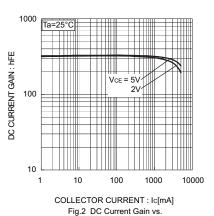
^{*1} Pulsed

^{*2} See switching time test circuit

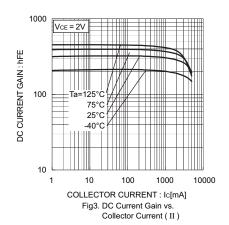
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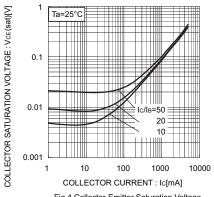
•Electrical characteristic curves

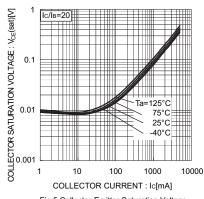


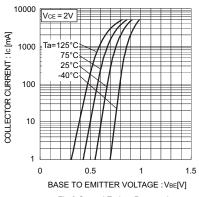


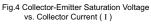
Collector Current (I)











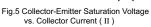
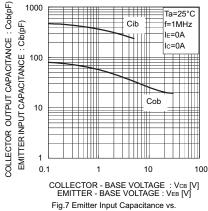
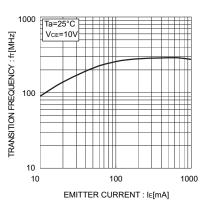


Fig.6 Ground Emitter Propagation Characteristics





100 Single pulse

100 OCCULECTOR TO EMITTER VOLTAGE: VCE[V]

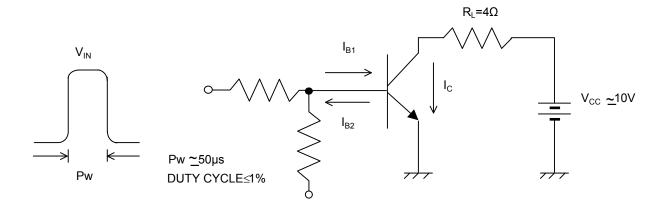
.7 Emitter Input Capacitance vs. Emitter-Base Voltage Collector Output Capacitance vs. Collector-Base Voltage

Fig.8 Gain Bandwidth Product vs. Emitter Current

Fig.9 Safe Operating Area

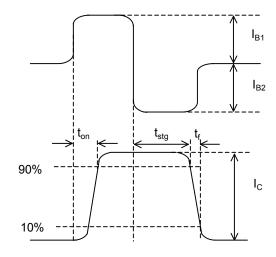
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•Switching time test circuit



BASE CURENT WAVEFORM

COLLECTOR CURRENT WAVEFORM



2009.12 - Rev.A

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